Structure, stress and mechanical properties of Mo-AI-N sputter-deposited thin films: role of point defects

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Context and motivation

- The aim of the present study is to gain a better understanding on phase formation, defect concentration, and mechanical properties when AI substitutes for Mo in Mo-AI-N coatings.
- We combine thin film growth experiments and density functional theory (DFT) calculations to study the importance of point defects
- $Mo_{1-x}Al_xN_y$ thin films with Al fraction x = 0 to 0.5 and nitrogen-tometal ratio y = 0.78 to 1.38 were deposited by reactive magnetron cosputtering [1].
- · Our experimental findings are compared and discussed with previous literature works [2,3].

Experimental procedure

- Base pressure : $p_0 \le 6 \cdot 10^{-6}$ Pa
- Two separate targets: Mo, Al
- DC power supply
- Ar+N₂ plasma discharge with fixed Ar (25 sccm) and N₂ (20 sccm) flow rate
- Working pressure: 0.30 Pa
- Substrate bias voltage: -60 V
- Substrate temperature: 300°C and 500°C - Film thickness: ~300 nm
- The AI content in Mo1-xAIxNy alloy was

varied by adjusting the DC power supply of Mo and Al cathodes - Stress is determined in situ using wafer

curvature (MOSS technique)

Deposition (reactive unbalanced magnetron)



DFT calculations

- VASP code - Pseudo potential PAW method GGA

cut-off 600 eV

Cubic rocksalt structure



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- Special Quasirandom Structure (SQS) approach to simulate Mo1-xAlxNy solid solutions
- ×2×2 supercells (64 atoms) Elastic constants obtained from strain/stress
- method [x] Polycrystalline Young modulus calculated using the Voigt-Reuss homogenization [x]

Microstructural characterization



SEM cross-section views

For x=0, stoichiometry close to MoN_{0.75}

- N-deficient films for low AI content (up to x=0.1)
- Increase of N content from 42 at.% to 55 at.% with incorporation of AI content despite constant N2 flow
- Two distinct regimes evidenced, related to different nitrogen affinity with increasing Al content · DFT calculations predicts stabilization of cubic
- structure with increasing AI fraction At low AI content (x=0.12), N and Me vacancies are thermodynamically favorable



Columnar growth evidenced for Al-rich films

DFT calculations – Phase stability

Compact microstructure



 Cubic rock-salt Mo_{1-x}Al_xN_y alloys with (001) preferred orientation
Decrease of a₀ lattice parameter with Al content predicted by DFT for defect-free MoAIN

Expansion of a₀ observed experimentally is contributed to a decrease in N vacancy concentration with increasing x





Blackman diagram





Non-monotonous variation of hardness and

- Maximum hardness value of ~33 GPa obtained for Mo_{0.81}Al_{0.19}N_{1.13} film deposited at 350 °C
- Complex dependence of elastic properties of Mo1-xAlxNy alloys to point defects
- beneficial in retaining the ductile properties of Mo-Al-N compared to Me ones

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Point defects, especially N vacancies below x = 0.12 and metal vacancies above this value, play a key role in the compositional dependence of the lattice constant, Young modulus, and shear elastic constant of Mo1_AIN, alloys

CONCLUSIONS

- The incorporation of AI into MoN is accompanied by a significant variation in the nitrogen content from 44% (x = 0) to 58% (x = 0.5) despite a constant N₂ partial pressure during deposition
- It is evidenced that ternary Mo1-xAlxNy alloys with low Al content (x = 0.02-0.12) tend to stabilize primarily N vacancies in the concentration between 10% and 20%, while the incorporation of a higher Al fraction (up to x = 0.5) results in the formation of less defective films
- Films with larger Al content (x = 0.25 and x = 0.5) exhibit worse mechanical properties (H \sim 27 GPa and elastic modulus ~245 GPa), which could be explained by more covalent bonding

-501 -750 -1250 150 180 210 240 270 300

In situ wafer curvature

Stress analysis





 Non-monotonous evolution with Al content contribution of tensile stress source for x=0.50 (columnar growth)

Mechanical properties

Nanoindentation tests (XP Nanoindentor MTS) with a Berkovich indente Transverse sound velocity measurements from Brillouin Light Scattering [6]

(GPa)

Al/(Al+Mo), x

- C44 elastic constant
- N vacancies are found to be more







ο.4 sin²ψ







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